To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

Phase-out/Discontinued

2SK3295

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

DESCRIPTION

The 2SK3295 is N-Channel MOS FET device that features a low on-state resistance and excellent switching characteristics, designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3295	TO-220AB
2SK3295-S	TO-262
2SK3295-ZK	TO-263(MP-25ZK)
2SK3295-ZJ	TO-263(MP-25ZJ)

FEATURES

- 4.5 V drive available
- Low on-state resistance
  $R_{DS(on)1}$ = 18 mΩ MAX. (V_{GS} = 10 V, I_D = 18 A)
- Low gate charge
  Q_G = 16 nC TYP. (I_D = 35 A, V_{DD} = 16 V, V_{GS} = 10 V)
- Built-in gate protection diode
- Surface mount device available

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	20	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±20	V
Drain Current (DC) (T_C = 25°C)	$I_{D(DC)}$	±35	A
Drain Current (Pulse) [Note]	$I_{D(pulse)}$	±140	A
Total Power Dissipation (T_A = 25°C)	P_{T1}	1.5	W
Total Power Dissipation (T_C = 25°C)	P_{T2}	35	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

Note PW ≤ 10 μs, Duty Cycle ≤ 1%

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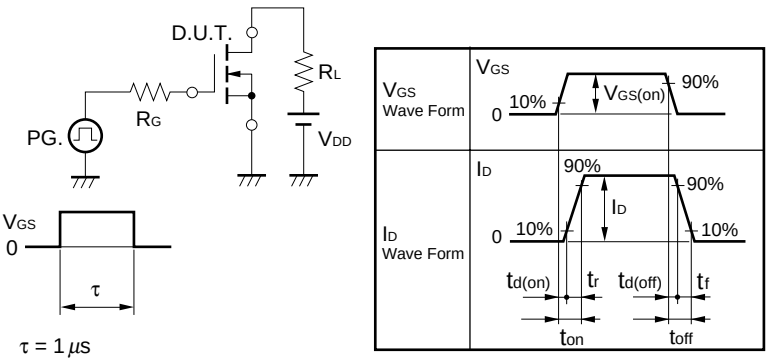
Printed in Japan

The mark ★ shows major revised points.

ELECTRICAL CHARACTERISTICS(T_A = 25°C)

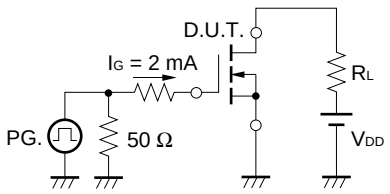
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 20 V, V_{GS} = 0 V			10	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Gate Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10 V, I_D = 1 mA	1.0		2.5	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 18 A	7.5			S
Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = 10 V, I_D = 18 A		13	18	mΩ
	$R_{DS(on)2}$	V_{GS} = 4.5 V, I_D = 18 A		21	27	mΩ
Input Capacitance	C_{iss}	V_{DS} = 10 V		720		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		370		pF
Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		180		pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = 10 V , I_D = 18 A		85		ns
Rise Time	t_r	$V_{GS(on)}$ = 10 V		2000		ns
Turn-off Delay Time	$t_{d(off)}$	R_G = 10 Ω		65		ns
Fall Time	t_f			270		ns
Total Gate Charge	Q_G	V_{DD} = 16 V		16		nC
Gate to Source Charge	Q_{GS}	V_{GS} = 10 V		3.1		nC
Gate to Drain Charge	Q_{GD}	I_D = 35 A		5.2		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 35 A, V_{GS} = 0 V		1.0		V
Reverse Recovery Time	t_{rr}	I_F = 35 A, V_{GS} = 0 V		28		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μs		14		nC

TEST CIRCUIT 1 SWITCHING TIME



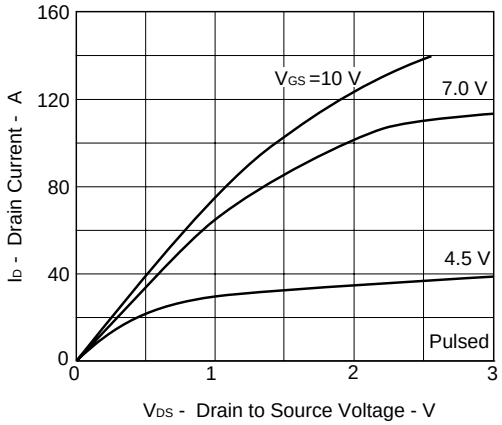
τ = 1 μs
Duty Cycle ≤ 1%

TEST CIRCUIT 2 GATE CHARGE

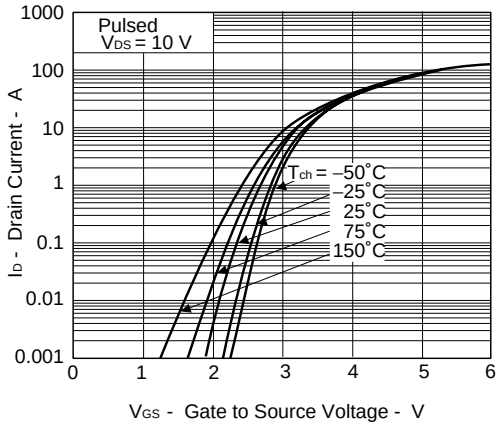


TYPICAL CHARACTERISTICS (T_A = 25°C)

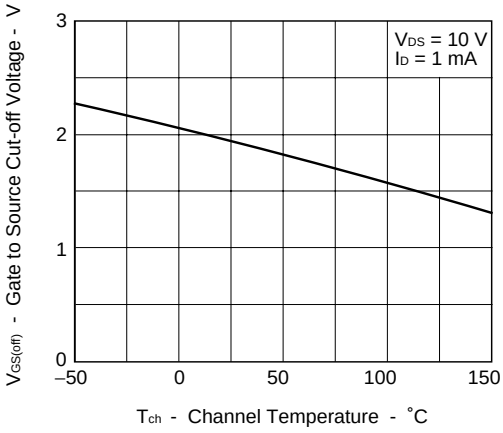
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



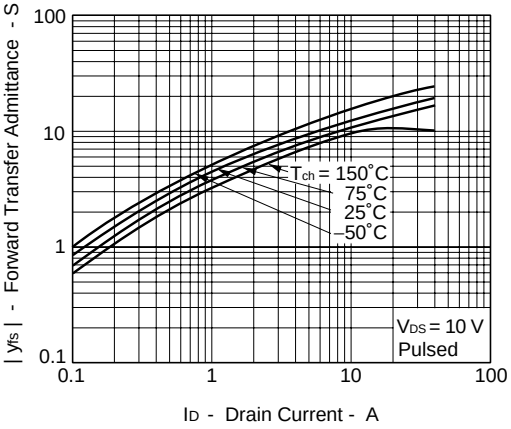
FORWARD TRANSFER CHARACTERISTICS



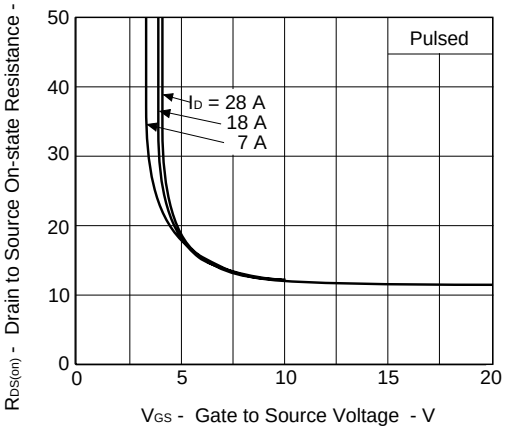
GATE TO SOURCE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



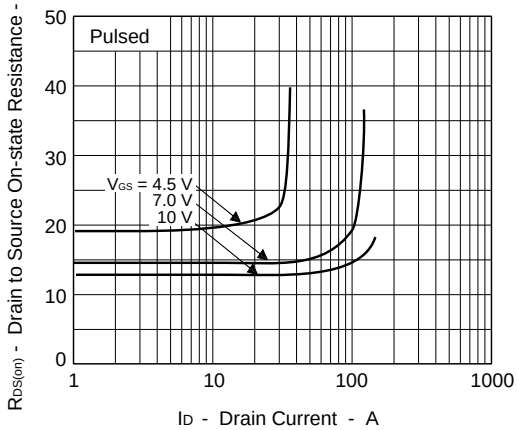
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



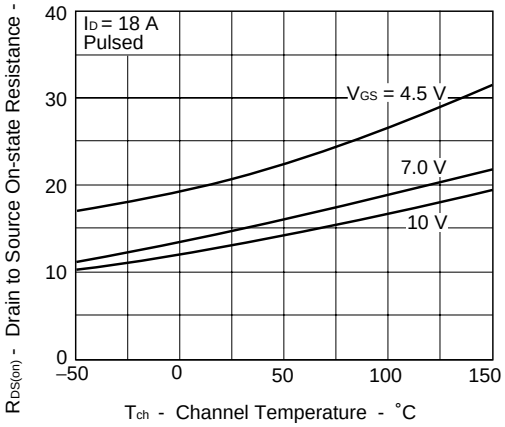
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



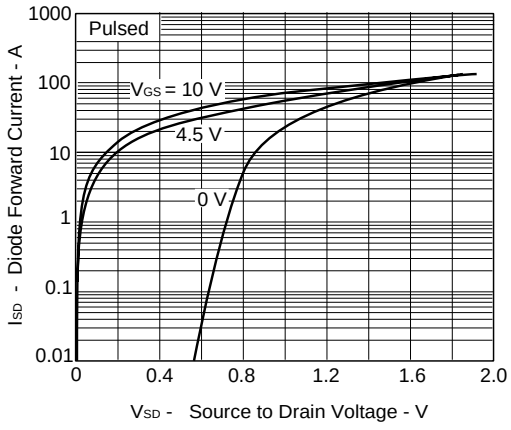
DRAIN TO SOURCE ON-STATE
RESISTANCE vs. DRAIN CURRENT



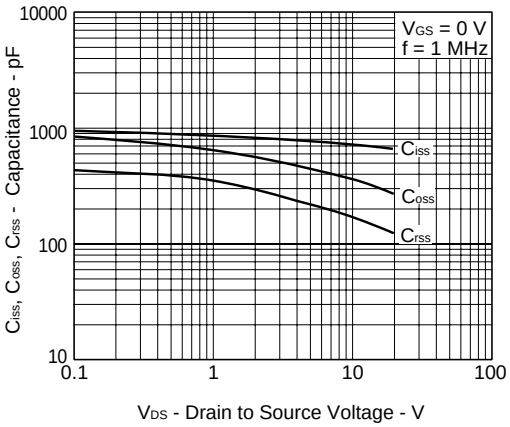
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



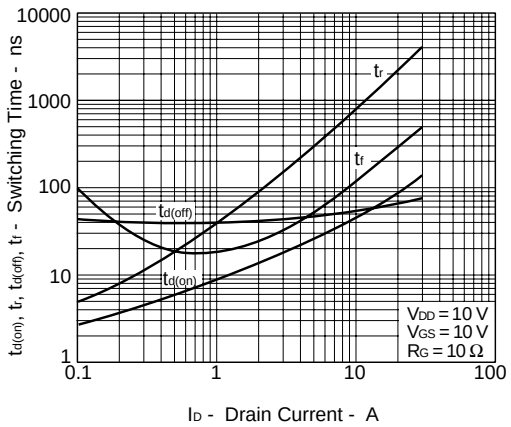
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



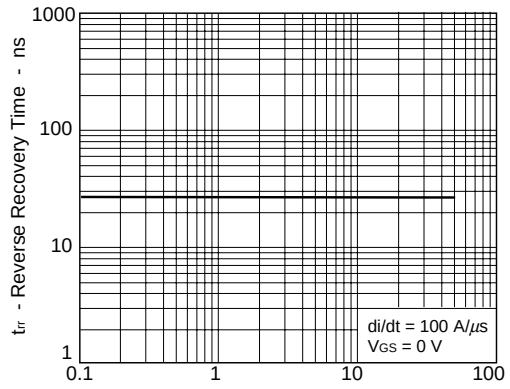
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



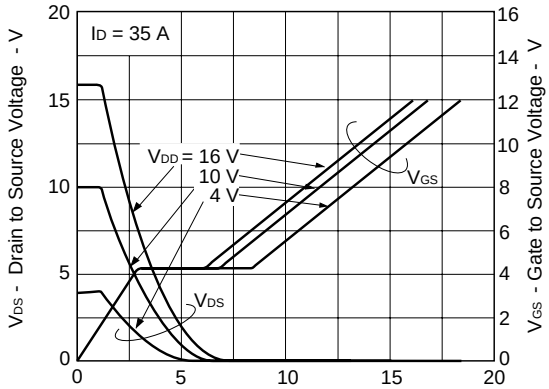
SWITCHING CHARACTERISTICS



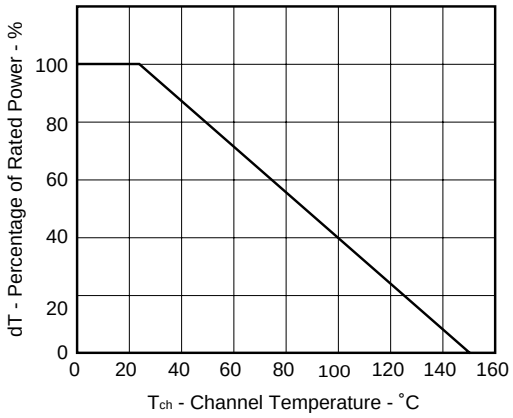
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



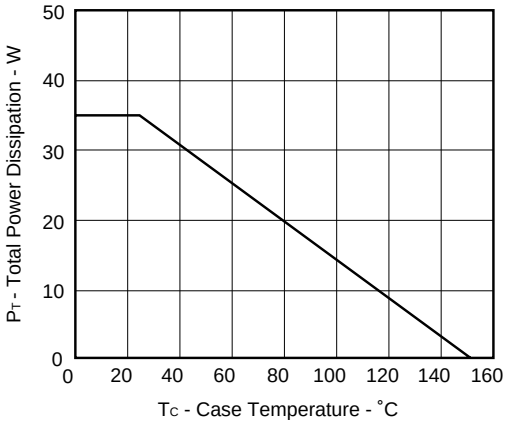
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



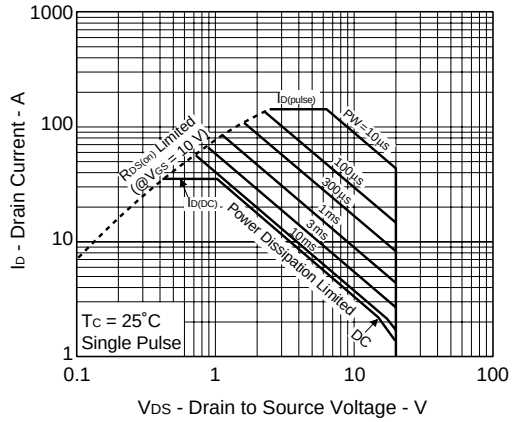
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



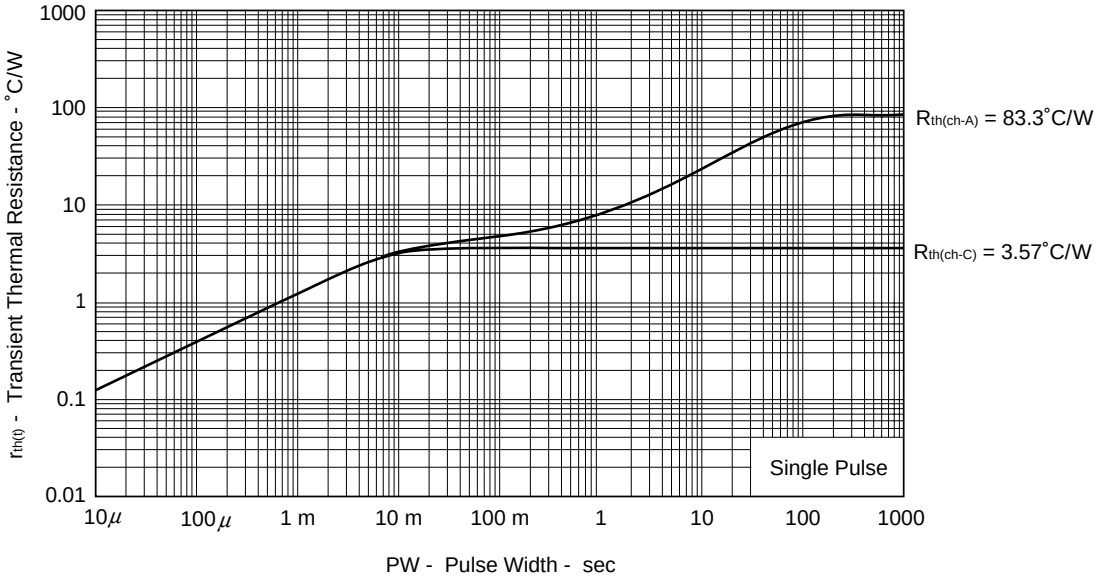
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



★ FORWARD BIAS SAFE OPERATING AREA

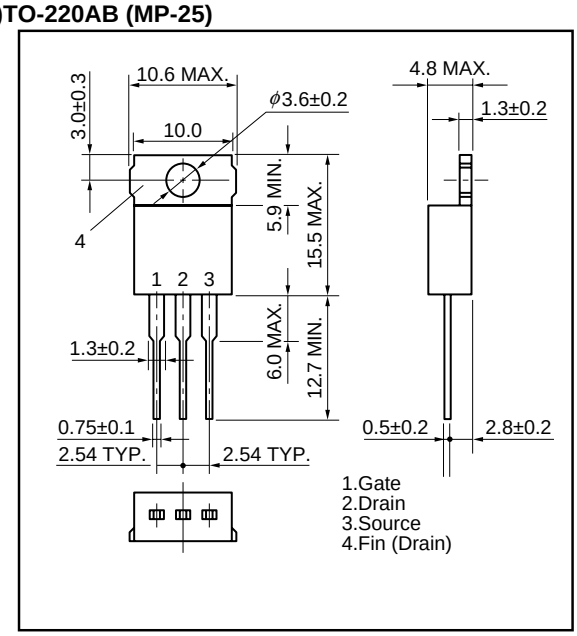


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

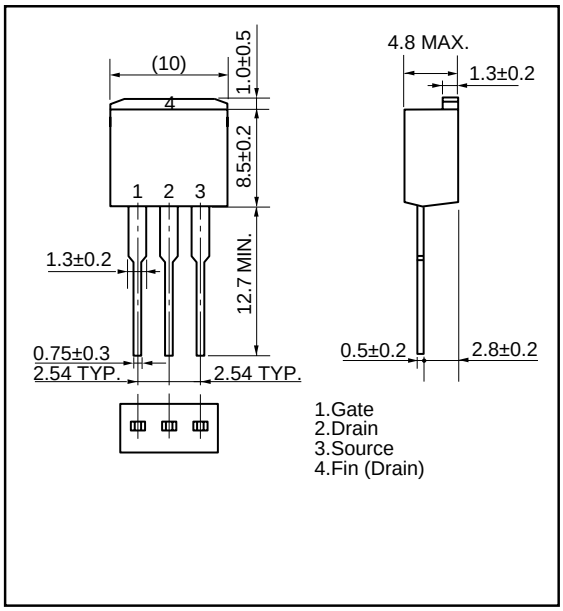


PACKAGE DRAWINGS (Unit : mm)

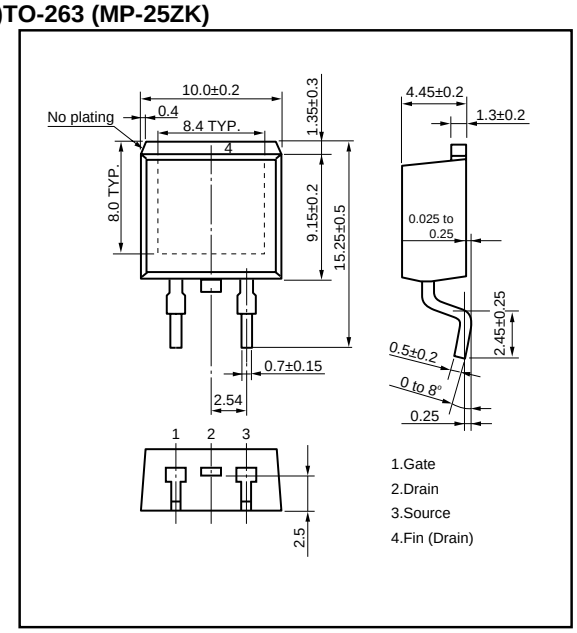
1)TO-220AB (MP-25)



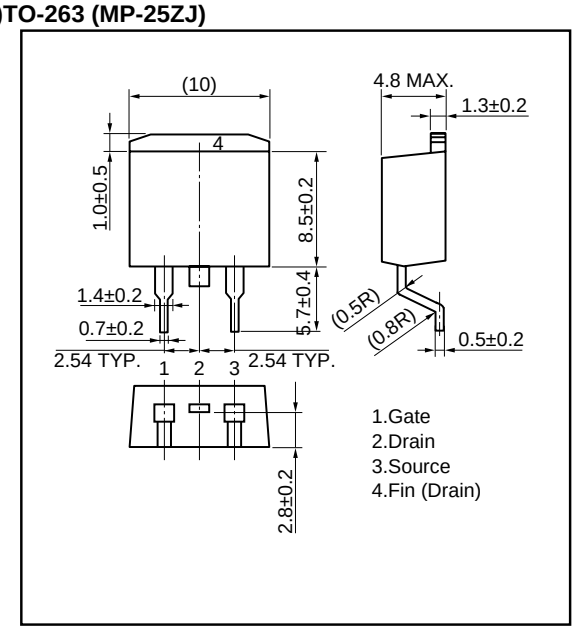
2)TO-262



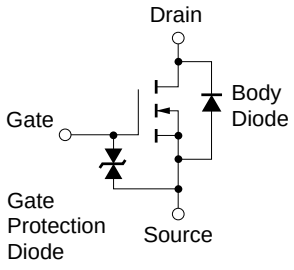
3)TO-263 (MP-25ZK)



4)TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.
When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

[MEMO]

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